



HFZT

RB751M9-40

Schottky Barrier Diode

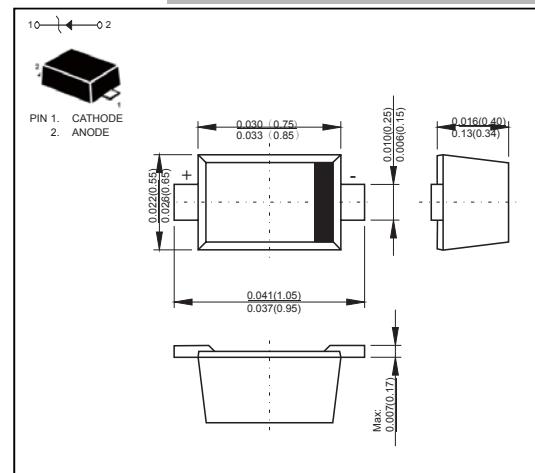
VOLTAGE RANGE: 30V

Features

- VR 30V
- IO 30mA
- Low Forward Voltage Drop

MECHANICAL DATA

- Case: SOD-923 Small Outline Plastic Package
- Polarity: Color band denotes cathode end
- Mounting Position: Any



MAXIMUM RATINGS AND CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified

Item	Symbol	Unit	Conditions	Limit
Reverse Voltage	VR	V		30
Repetitive Peak Reverse Voltage	VRRM	V		40
Non-Repetitive Peak Forward Current	IFSM	mA	8.3 ms single half sine-wave	200
Continue Forward Rectified Current	IO	mA		30
Junction Temperature	TJ	°C		125
Storage Temperature	TSTG	°C		-55 to +125

Electrical Specification ($T_A=25^\circ\text{C}$ unless otherwise specified)

Item	Symbol	Unit	Conditions	Min	Max
Breakdown Voltage	VR	V	IR=0.5uA	30	
Reverse Leakage Current	IR	uA	VR=30V		0.5
Forward Voltage	VF	V	IF=1mA		0.37
Capacitance	CD	pF	VR = 1V, f = 1MHz	2(typical)	

Marking C

Packing Information

Device	Package	Shipping
RB751M9-40	SOD-923	8000/Tape&Reel